

www.ijbar.org

ISSN 2249-3352 (P) 2278-0505 (E)

https://zenodo.org/records/14632225 Cosmos Impact Factor-5.86

SIMULATION OF BUCK CONVERTER USING SIMULINK AND SPICE TOOL

Dr.EVenkatesh¹,M.Vandhana²,S.Tejaswini³,P.KomaliKeethana⁴

¹AssistantProfessor,Dept.ofEEE,MallaReddyEngineeringCollegeforWomens,Hyderabad,

²³⁴ResearchStudent,Dept.ofEEE,MallaReddyEngineeringCollegeforWomens,Hyderabad

This article looks at how the power converter designer can use the system–level and detailed models together to enable exploration of the design space and also achieve high confidence in the results. An example of this process will be shown using MathWorks system–level modelling tools Simulink® and Simscape $^{\rm TM}$ with detailed SPICE subcircuits representing Infine on Automotive MOSFETs.

Introduction

During the development of electrical power converters, numeri – cal simulations are typically used during the concept and feasibil – ity study. The simulation models need to include both the analog circuit and the corresponding digital controllers. Examples of the design questions that models can help answer include:

Whichtopologyshouldbeused?

- · Foragiventopology, what performance can be achieved?
- · WhatPWMswitchingfrequencyshouldbeused?
- What values and ratings are required for the passive components?
- · Whatkindofpowerswitchshouldbeused:
 - type(likeMOSFETsorIGBTsorBJTs)?
 - technology and voltage ratings (like Infineon's OptiMOS™ or CoolMOS™) and materials (likeSiorSiCorGaN)?
- What are the requirements on the gate driver circuits including minimum required dead-time?

Finally, based on previous assessments:

- System efficiency and component losses may be estimated, and subsequentlyasuitablecoolingsystemcanbedeveloped;
- The trade-off of system efficiency with EM compatibility can be investigated. Switching losses and EMI are both dependent on switching frequency and powers witch slewrate.

SPICE simulation tools are the go-to solution for circuit designers. However, the design steps described depend on being able to sim-ulate the power converter in reasonable time. Circuit simulation tools like Simscape™Electrical™havesimpledevicemodelsthatareessentially idealswitches plustabulated switching losses which meet this efficient simulation need. Moreover, tight integration with Simulink® means that the digital controller is also included in the simulation with noneedfor co-simulation. However, the ideal switch assumption creates some uncertainty for the later design steps focused on determining efficiency and fine-tuning the design. This uncertainty can be addressed by using detailed SPICE device models developed by the component manufacturer. In this paper, a process is defined that $enables fast \, exploration \, of the \, design \, space whilst also capitalizing on \,$ the detailed foundry SPICE compo-nent models. Central to the process ismakinguseofmultiplemod-elswithdifferinglevelsoffidelity, matching the model the specific design question to be answered. Also importantis the use of low-fidelity levels to pre-initialize detailed simulation modelstherebyreducing initialization time.

Buckconverterdesignexample

 $A48V/12VDC/DC step-down buck converter shown in Figure 1 is used as the example in this paper. Abuck converter steps down the input voltage (V_IN) to a lower-level output voltage (V_OUT), and the main equation characterizing its behavior is given by:$

Equation 1

$$d = \frac{V_OUT}{} \Rightarrow V_OUT = d*V_IN \ V_IN$$

where d represents the duty cycle of the high side power switch (HS_SW). The duty cycle of the low side power switch (LS_SW) is given by d'defined by:

Equation2

$$d! = 1-d$$

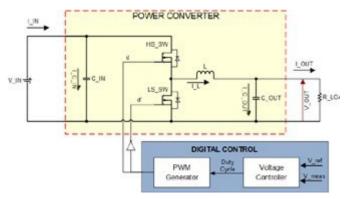


Figure 1: Structure of buck (Step-Down) DC/DC power converter

Based on the reference voltage (V_ref) and measured output volt-age (V_meas), the discrete-time proportional plus integral voltage controller calculates required duty cycle(d).

Infineon SPICE MOSFET model

SPICE ("Simulation Program with Integrated Circuit Emphasis") simulators are the most commonly–used technology for analog circuit simulation. Therefore, as de–facto industrial standard, many semiconductor manufacturers develop SPICE models of their products to support circuit design.

Infineon's portfolio of automotive qualified OptiMOSTM power MOSFETs offer benchmark quality in a range from 20V–300V, diversified packages and an $R_{ds(on)}$ down to 0.55 $m\Omega$. Structure of typical Infineon's SPICE model of MOSFET is shown on Figure 2. This behav–ioral MOSFET model[1] describes both the electrical and thermal characteristics of the powers witch.



www.ijbar.org

ISSN 2249-3352 (P) 2278-0505 (E)

https://zenodo.org/records/14632225 Cosmos Impact Factor-5.86

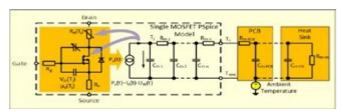


Figure 2: Schematic of Infine on 's SPICEMOSFET model structure The model reflects that current flowing through the MOSFET causes changes in semiconductor temperature which, in – turn, influences the MOSFET electrical parameters such as charge carrier mobil – ity, voltage threshold, drain resistance, gate – drain capacitance and gate-source capacitance. Referring to Figure 2, thermal behavior is modeled in the following way: a current source (P_{ν}) representing MOSFET dissipated power injects the heat into the PN – junction (T_{j}), and that heat is then propagated all the way through MOSFET package to the case (T_{c}). The thermal dynamics is modeled as a Cauer network made up of lumped thermal resistances (R_{thi}) and thermal capacitances (C_{thi}). By means of analog simulation of the thermal

Importing a subcircuit into Simscape

thickness/numberofPCBlayers(R_{thPCB} and C_{thPCB}).

Simscape[5]fromMathWorksprovidesablockdiagramenviron-ment to model multi-domain systems, including electrical, mechan- ical, magnetic and thermal aspects. The accompanying Simscape language expresses the underlying physics using differential equations, associated algebraic constraints, events and mode charts.

model, the optimum cooling/heat sink ($R_{th\ HS}$ and $C_{th\ HS}$) can be determined for given design parameters like load current, maximum

allowed junction temperature (T_j) , ambient temperature (T_{amb}) and



Figure 3: Infineon's Automotive MOSFETIAUT 300 NO 8S 5 NO 12 in TOLL (PG-HSOF-8)

SimscapeElectrical™[6]isabletoimportatargetedsetofSPICEdevice models, such as MOSFETs, into an equivalent Simscape lan- guage implementation [7]. Simscape's tight integration with Simu- link then enablessimulatingboththedigitalcontrollerandtheana-logelectronics withasinglesolver,this resulting in a more efficient simulation than cosimulation between different simulation tools.

The SPICE model import capability is used to import the Infineon IAUT300N08S5N012 [2][4] device (shown on Figure 3) into Simscape.OnceimportedintoSimscape,someminoreditsweremadetothe Simscape code to provide access to the Cauer model states from the published block. Providing customized access to the inter– nal states is neededfortheinitialization process.

Simulation workflow

Having imported the Infineon device into Simscape, the next step is to create a Simulink model of the complete converter including the imported Infineon devices, remaining analog components and the controller. This is shown in Figure 4.

The controller is implemented using Simulink discrete-time library blocks, and the complete model is simulated using a variable-step solver so that the faster time constants associated with parasitics and the MOSFET charge model are accurately captured. The simu-

lation time for one controller PWM cycle is 2.3 seconds on an Intel $^{\circ}$ Core $^{\top}$ i7-9700 CPU@3.00 GHz running MATLAB version R2021b. This is fast enough to analyze circuit performance at current op- erating state, but not to assess circuit sensitivity to design parameters sweeps or to directly optimize the circuit parameters. Further-more, it is not fast enough to simulate to a periodic steady state which, given a thermal time constant of approximately 10 seconds, equates to 200,00020 kHz PWM cycles.

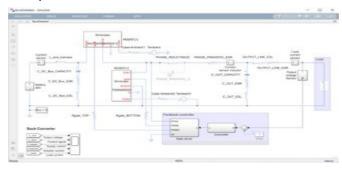


Figure4:Detailedmodelofthebuckconverter

 $To address the need to explore the design space efficiently, asys-tem-level version of the buck converter model created. For this, the imported MOSFET device models are replaced with ideal switches with fixed on-resistance set to the datasheet <math>R_{ds(on)}$ value. This is shown in Figure 5. Some of the faster parasitics are also omitted.

suchastheMOSFETleadinductances. This system-level model is fixed temperature, the user setting an appropriate $R_{ds(on)}$ value for the assumed junction temperature. The model takes around 0.05 seconds to simulate one PWM cycle, 46 times faster than the detailed model. As the rearenother maltime constants, the slowest

dynamicis nowas sociated with the voltage regulation and is of the order of 5 ms or 100 PWM cycles. Hence simulation to steady state takes approximately 5 seconds.

Withthissimulationperformance, the system-level model can be used to thoroughly explore the design space and optimize the con-troller. With the main design decisions made, the final step is to validate the design using the detailed simulation model that makes use of the Infineon MOSFET models. This validation is typically reported at a set of operating points defined by load power and ambient temperature. However, we have seen that to simulate the detailed model to steady state requires 200,000 PWM cycles which is not practical if each cycle takes 2.3 second stosimulate.



Figure5:System-levelSimulinkmodelofthebuckpowerconverter

To initialize the detailed model at a specified operating point, an iterative approach involving multiple models is proposed. Overall, the idea is to separate out slower time constants into separate models that run faster. Before explaining in more detail, one more model is required which is one that models the MOSFET and envi-ronment thermal states only. This is shown in Figure 6.

Page | 636 Index in Cosmos



www.ijbar.org

ISSN 2249-3352 (P) 2278-0505 (E)

https://zenodo.org/records/14632225 Cosmos Impact Factor-5.86

implement two or three MOSFETs in parallel for both the high-side and low-sideswitches. The important thing to note is that there can be a high-level of confidence in this result given that the validated foundry SPICE MOSFET models were used to generate them and that the results are for the actual circuit. This gives a higher-level of confidence than the sometimes-used alternative based on data-sheet plots of on-state and switching losses for a representative test circuit.

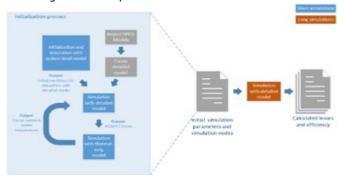


Figure 8: Proposed simulation flow for switching power converters

A summary of the overall process followed is shown in Figure 8. The process is implemented as a MATLAB® script which can be downloaded from MathWorks File Exchange [3]. The script takes four minutes to run and produce the results in Figure 7. For comparison, it was determined that running the non-linear model from a non-initialized state to get to the same results takes of the order of a day.

Conclusions

It has been shown how detailed SPICE foundry semiconductor models can be used in an application circuit model to make high-confidence predictions about expected circuit performance. The challenge of initializing a model with widely varying time con-stants and with a periodic steady state has been tackled with a two-pronged approach. Firstly, avoidance of slow co-simulation is achieved by importing SPICE subcircuits into Simulink, and solving the complete analog system plus controller using a variable-step solver. Secondly, the steady state is found by using multiple models with differing fidelity levels with a simple iterative scheme. The end result is an end-to-end designand simulation capability that is faster than if working solely with a SPICE simulation engine.

References

- März,M.,Nance,P., "Thermal Modeling of Power-electronic Sys-tems," February 2000. Available online at www.infineon.com/ dgdl/Thermal+Modeling.pdf?fileId=db3a30431441fb5d011472f d33c70aa3...
- Huang, A., "Infineon OptiMOSTM Power MOSFET Datasheet Explanation," Application Note AN 2012-03 V1.1 March 2012. Avail-able online at www.infineon.com/dgdl/Infineon-MOSFET_Opti-MOS_datasheet_explanation-AN-v01_00-EN.pdf?fileId=db3a304 33b47825b013b6b8c6a3424c4.
- 3. Vuletic, R., Hyde, R., John., D., "Infineon Buck Simscape Example," MathWorks File Exchange, February 2022. Available online at https://de.mathworks.com/matlabcentral/fileexchange/106925-infineon-buck-simscape-example.
- Availableonlineathttps://www.infineon.com/cms/en/product/ power/mosfet/automotive-mosfet/iaut300n08s5n012/
- 5. mathworks.com/help/physmod/simscape
- 6. mathworks.com/help/physmod/sps
- 7. mathworks.com/help/physmod/simscape/get-started-with-sim-scape-language.html

Page | 637

Index in Cosmos

Dec 2024, Volume 14, ISSUE 4
UGC Approved Journal